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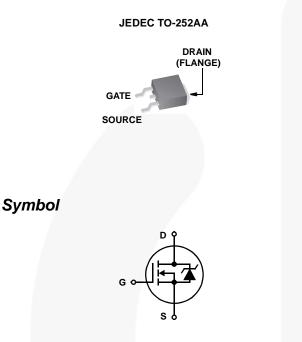
HUF76609D3S

Data Sheet

October 2013

N-Channel Logic Level UltraFET Power MOSFET 100 V, 10 A, 165 $m\Omega$

Packaging



Features

- Ultra Low On-Resistance
 - $r_{DS(ON)} = 0.160\Omega, V_{GS} = 10V$
 - $r_{DS(ON)} = 0.165\Omega, V_{GS} = 5V$
- Simulation Models
 - Temperature Compensated PSPICE® and SABER™ Electrical Models
 - Spice and SABER Thermal Impedance Models
 - www.Fairchildsemi.com
- Peak Current vs Pulse Width Curve
- UIS Rating Curve
- Switching Time vs R_{GS} Curves

Ordering Information

PART NUMBER	PACKAGE	BRAND
HUF76609D3ST	TO-252AA	76609D

Absolute Maximum Ratings T_C = 25^oC, Unless Otherwise Specified

	HUF76609D3ST	UNITS
Drain to Source Voltage (Note 1)V _{DSS}	100	V
Drain to Gate Voltage (R _{GS} = 20kΩ) (Note 1)	100	V
Gate to Source Voltage	±16	V
Drain Current		
Continuous (T _C = 25° C, V _{GS} = 5V)I _D	10	А
Continuous (T _C = 25° C, V _{GS} = 10V) (Figure 2)I _D	10	А
Continuous (T _C = 100° C, V _{GS} = 5V)	7	А
Continuous (T _C = 100 ^o C, V _{GS} = 4.5V) (Figure 2)	7	А
Pulsed Drain Current I _{DM}	Figure 4	
Pulsed Avalanche Rating UIS	Figures 6, 17, 18	
Power Dissipation P _D	49	W
Derate Above 25 ^o C	0.327	W/ ^o C
Operating and StorageTemperature	-55 to 175	°C
Maximum Temperature for Soldering		
Leads at 0.063in (1.6mm) from Case for 10sTL	300	°C
Package Body for 10s, See Techbrief TB334T _{pkg}	260	°C
NOTE:		

1. $T_J = 25^{\circ}C$ to $150^{\circ}C$.

CAUTION: Stresses above those listed in "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress only rating and operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied.

Product reliability information can be found at http://www.fairchildsemi.com/products/discrete/reliability/index.html For severe environments, see our Automotive HUFA series.

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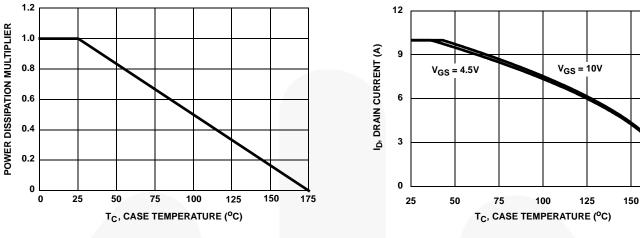
PARAMETER	SYMBOL	TEST	CONDITIONS	MIN	TYP	MAX	UNITS
OFF STATE SPECIFICATIONS	!	+			<u></u>	!	+
Drain to Source Breakdown Voltage	BV _{DSS}	I _D = 250μA, V _{GS} = 0V (Figure 12)		100	-	-	V
		$I_D = 250\mu A$, $V_{GS} = 0V$, $T_C = -40^{\circ}C$ (Figure 12)		90	-	-	V
Zero Gate Voltage Drain Current	I _{DSS}	$V_{DS} = 95V, V_{GS} = 0V$		-	-	1	μA
		$V_{DS} = 90V, V_{GS} = 0V$, T _C = 150 ^o C	-	-	250	μΑ
Gate to Source Leakage Current	I _{GSS}	$V_{GS} = \pm 16V$		-	-	±100	nA
ON STATE SPECIFICATIONS							-1
Gate to Source Threshold Voltage	V _{GS(TH)}	$V_{GS} = V_{DS}, I_{D} = 250 \mu$	ιA (Figure 11)	1	-	3	V
Drain to Source On Resistance	rDS(ON)	I _D = 10A, V _{GS} = 10V (Figures 9, 10)		-	0.130	0.160	Ω
	, í	I _D = 7A, V _{GS} = 5V (Fi	gure 9)	-	0.135	0.165	Ω
		$I_{D} = 7A, V_{GS} = 4.5V$ (Figure 9)	-	0.140	0.168	Ω
THERMAL SPECIFICATIONS						ļ	4
Thermal Resistance Junction to Case	R _{θJC}	TO-252		-	-	3.06	°C/W
Thermal Resistance Junction to Ambient	R _{θJA}	_		-	-	100	°C/W
SWITCHING SPECIFICATIONS (V_{GS} =	= 4.5V)						
Turn-On Time	ton	V _{DD} = 50V, I _D = 7A		-	-	77	ns
Turn-On Delay Time	t _{d(ON)}	$V_{GS} = 4.5V, R_{GS} = 20$	Ω	-	10	-	ns
Rise Time	t _r	_ (Figures 15, 21, 22)		-	41	-	ns
Turn-Off Delay Time	td(OFF)	-		-	30	-	ns
Fall Time	t _f	-		-	28	-	ns
Turn-Off Time	tOFF			-	-	87	ns
SWITCHING SPECIFICATIONS (V _{GS} \approx	= 10V)						-1
Turn-On Time	ton	$V_{DD} = 50V, I_D = 10A V_{GS} = 10V, R_{GS} = 24\Omega (Figures 16, 21, 22)$		-	-	36	ns
Turn-On Delay Time	t _{d(ON)}			-	6	-	ns
Rise Time	t _r			-	18	-	ns
Turn-Off Delay Time	t _{d(OFF)}			-	55	-	ns
Fall Time	tf			- 1	39	-	ns
Turn-Off Time	tOFF			-	-	141	ns
GATE CHARGE SPECIFICATIONS				7			-1
Total Gate Charge	Q _{g(TOT)}	$V_{GS} = 0V$ to 10V	V _{DD} = 50V,	-	13	16	nC
Gate Charge at 5V	Q _{g(5)}	$V_{GS} = 0V \text{ to } 5V$	$I_{\rm D} = 7A,$	-	7.3	8.8	nC
Threshold Gate Charge	Q _{g(TH)}	$V_{GS} = 0V \text{ to } 1V$	I _{g(REF)} = 1.0mA (Figures 14, 19, 20)	-	0.5	0.6	nC
Gate to Source Gate Charge	Q _{gs}	(Figures 14, 19, 20)	-	1.4	-	nC	
Gate to Drain "Miller" Charge	Q _{gd}			-	3.4	-	nC
CAPACITANCE SPECIFICATIONS	Ū		J				
Input Capacitance	C _{ISS}	V _{DS} = 25V, V _{GS} = 0V	,	-	425	•	pF
Output Capacitance	C _{OSS}	f = 1MHz		-	75		pF
Reverse Transfer Capacitance	C _{RSS}	(Figure 13)		-	22	-	pF

Electrical Specifications $T_C = 25^{\circ}C$, Unless Otherwise Specified

Source to Drain Diode Specifications

PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNITS
Source to Drain Diode Voltage	V _{SD}	I _{SD} = 7A	-	-	1.25	V
		I _{SD} = 4A	-	-	1.0	V
Reverse Recovery Time	t _{rr}	$I_{SD} = 7A$, $dI_{SD}/dt = 100A/\mu s$		-	92	ns
Reverse Recovered Charge	Q _{RR}	$I_{SD} = 7A$, $dI_{SD}/dt = 100A/\mu s$		-	273	nC

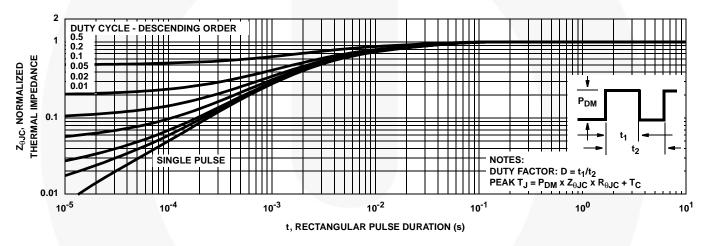
Typical Performance Curves







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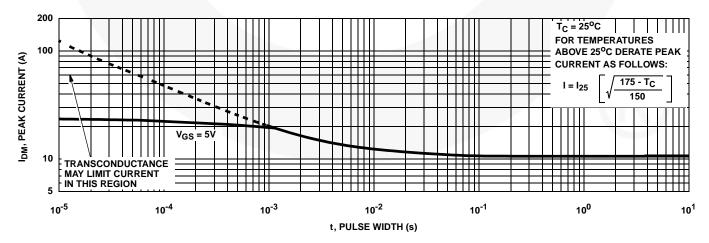


FIGURE 4. PEAK CURRENT CAPABILITY

Typical Performance Curves (Continued)

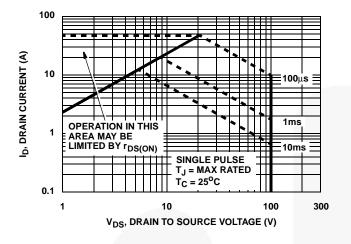


FIGURE 5. FORWARD BIAS SAFE OPERATING AREA

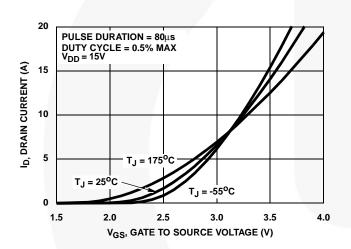
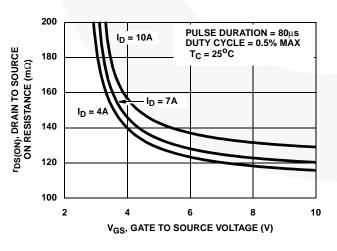
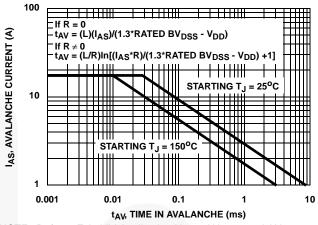


FIGURE 7. TRANSFER CHARACTERISTICS







NOTE: Refer to Fairchild Application Notes AN9321 and AN9322. FIGURE 6. UNCLAMPED INDUCTIVE SWITCHING

CAPABILITY

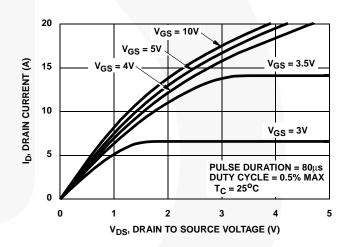


FIGURE 8. SATURATION CHARACTERISTICS

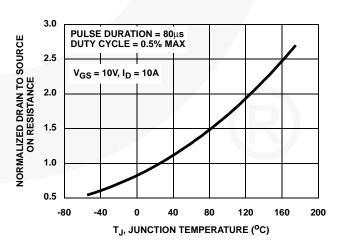
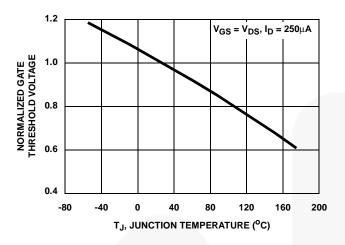


FIGURE 10. NORMALIZED DRAIN TO SOURCE ON RESISTANCE vs JUNCTION TEMPERATURE

Typical Performance Curves (Continued)





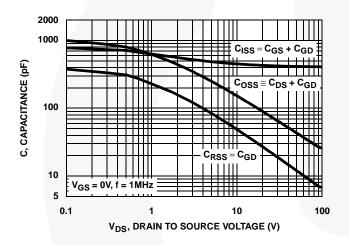


FIGURE 13. CAPACITANCE vs DRAIN TO SOURCE VOLTAGE

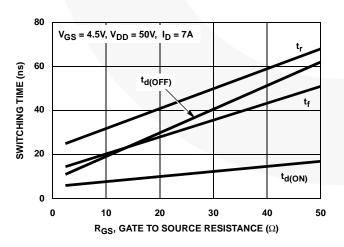


FIGURE 15. SWITCHING TIME vs GATE RESISTANCE

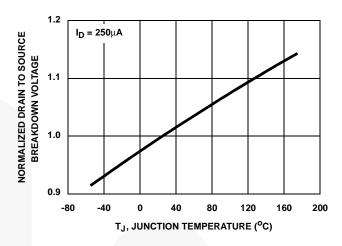
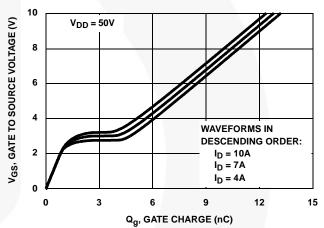


FIGURE 12. NORMALIZED DRAIN TO SOURCE BREAKDOWN VOLTAGE vs JUNCTION TEMPERATURE



NOTE: Refer to Fairchild Application Notes AN7254 and AN7260. FIGURE 14. GATE CHARGE WAVEFORMS FOR CONSTANT GATE CURRENT

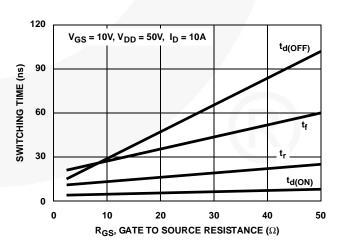


FIGURE 16. SWITCHING TIME vs GATE RESISTANCE

Test Circuits and Waveforms

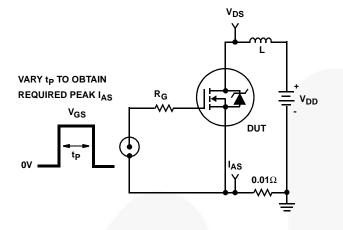


FIGURE 17. UNCLAMPED ENERGY TEST CIRCUIT

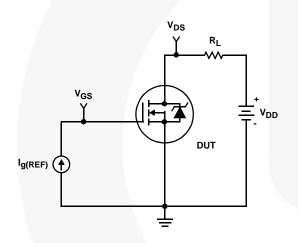


FIGURE 19. GATE CHARGE TEST CIRCUIT

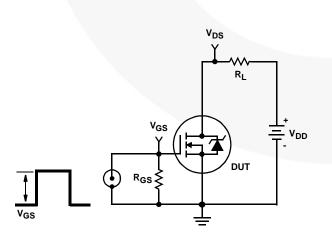


FIGURE 21. SWITCHING TIME TEST CIRCUIT

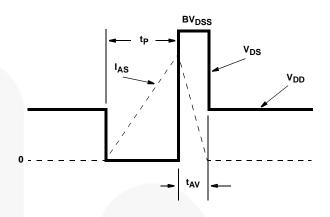


FIGURE 18. UNCLAMPED ENERGY WAVEFORMS

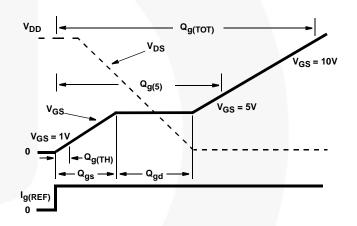


FIGURE 20. GATE CHARGE WAVEFORMS

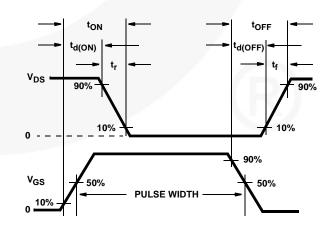
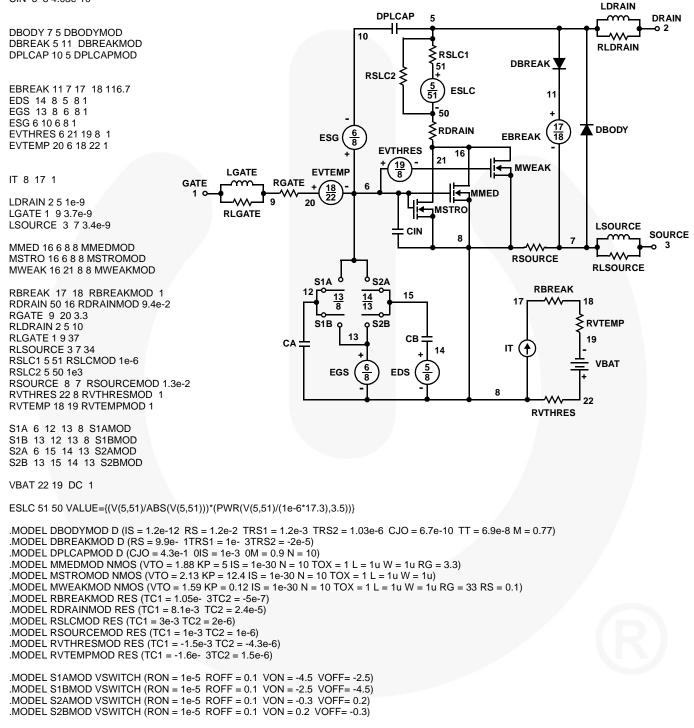


FIGURE 22. SWITCHING TIME WAVEFORM

PSPICE Electrical Model

.SUBCKT HUF76609D3 2 1 3 ; rev 23 August 1999

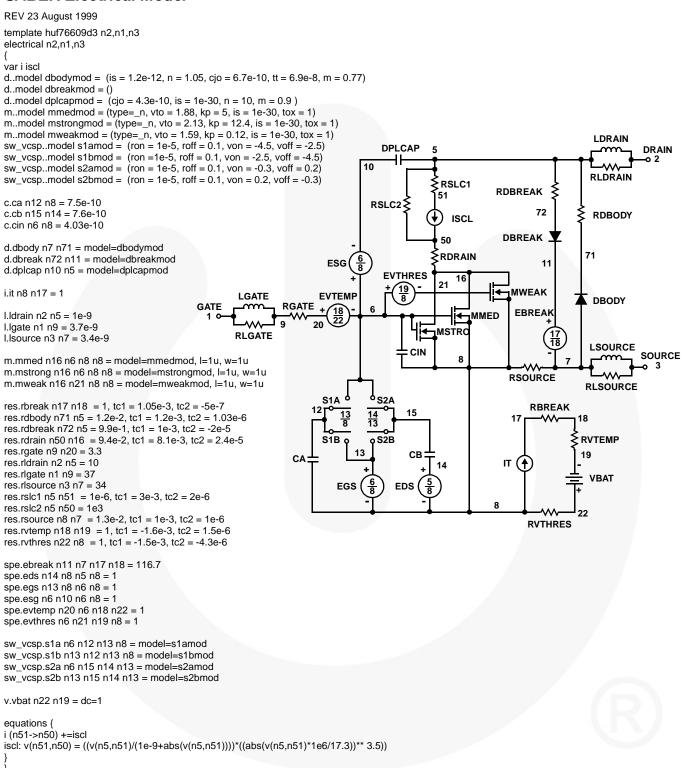
CA 12 8 7.5e-10 CB 15 14 7.6e-10 CIN 6 8 4.03e-10



.ENDS

NOTE: For further discussion of the PSPICE model, consult **A New PSPICE Sub-Circuit for the Power MOSFET Featuring Global Temperature Options**; IEEE Power Electronics Specialist Conference Records, 1991, written by William J. Hepp and C. Frank Wheatley.

SABER Electrical Model



SPICE Thermal Model

REV 23 August 1999 T76609d3

CTHERM1 th 6 9.50e-4 CTHERM2 6 5 2.40e-3 CTHERM3 5 4 3.90e-3 CTHERM4 4 3 4.10e-3 CTHERM5 3 2 5.60e-3 CTHERM6 2 tl 4.00e-2

RTHERM1 th 6 2.00e-2 RTHERM2 6 5 1.10e-1 RTHERM3 5 4 2.75e-1 RTHERM4 4 3 5.53e-1 RTHERM5 3 2 7.25e-1 RTHERM6 2 tl 7.56e-1

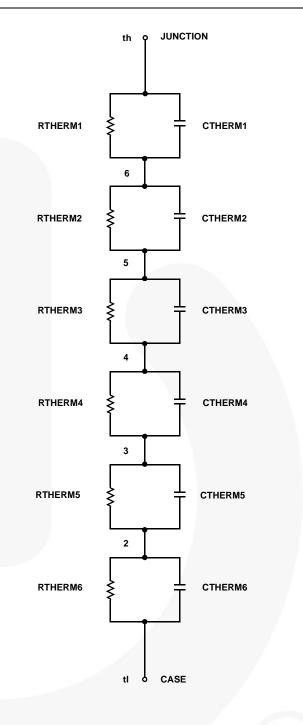
SABER Thermal Model

SABER thermal model t76609d3

template thermal_model th tl thermal_c th, tl

ctherm.ctherm1 th 6 = 9.50e-4ctherm.ctherm2 6 5 = 2.40e-3ctherm.ctherm3 5 4 = 3.90e-3ctherm.ctherm4 4 3 = 4.10e-3ctherm.ctherm5 3 2 = 5.60e-3ctherm.ctherm6 2 tl = 4.00e-2 rtherm.rtherm1 th 6 = 2.00e-2

rtherm.rtherm2 6 5 = 1.10e-1rtherm.rtherm3 5 4 = 2.75e-1rtherm.rtherm4 4 3 = 5.53e-1rtherm.rtherm5 3 2 = 7.25e-1rtherm.rtherm6 2 tl = 7.56e-1



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